

i) Which one is a better current source?

In general a good current source should not be too sensitive to fluctuations in voltage, temperature, etc.

large signal model:

$$I_C = I_S \exp\left(\frac{V_{BE}}{V_T}\right) \left(1 + \frac{V_{CE}}{V_A}\right)$$

↑  
non-ideal: changes in  $V_{CE}$  cause  $I_C$  to change.  
(early effect)

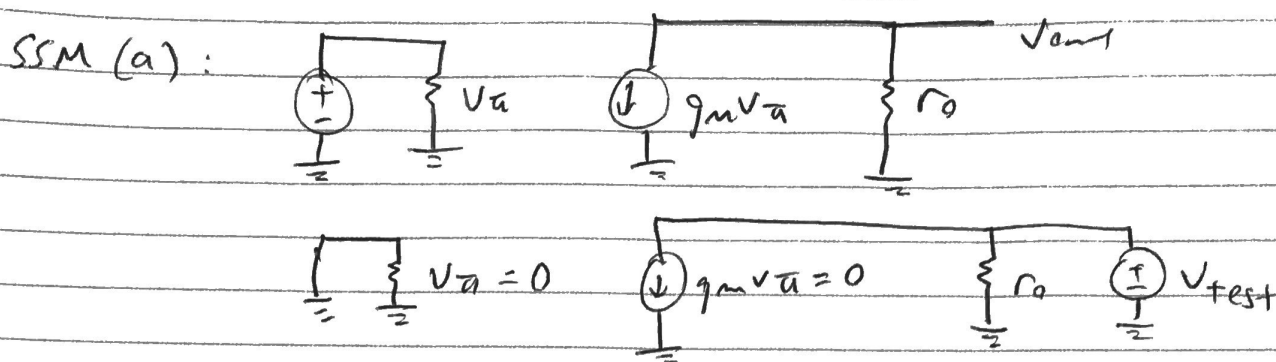
For (a),  $V_{BE} = V_0$

For (b),  $V_{BE} = V_0 - I_E R_E$

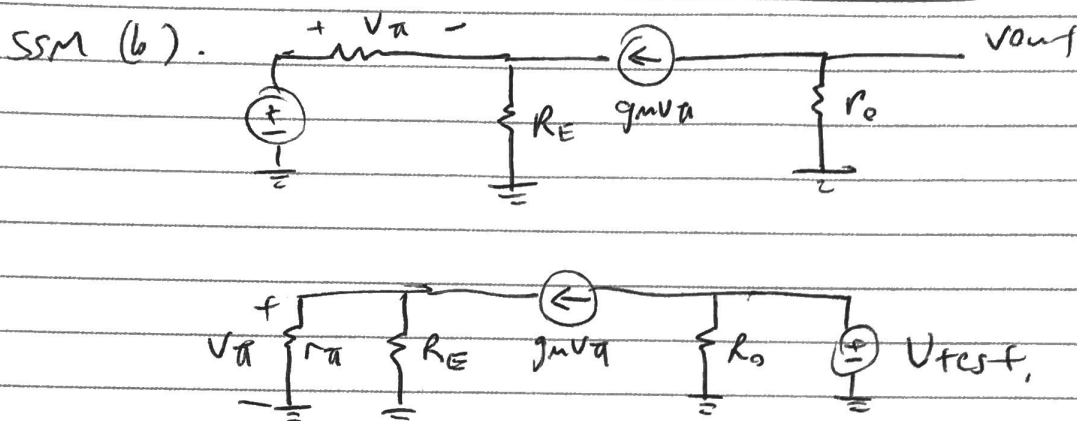
Due to the early effect, when  $V_{CE}$  increases,  $I_C$  also increases. However, for (b),  $V_{BE}$  also ~~decreases~~ <sup>decreases</sup> if  $I_E \approx I_C$  increases, which helps to lower  $I_C$  and thus mitigates the early effect nonideality. Thus (b) acts as a better current source because it is more resistant to changes in  $V_{CE}$ .

(Here, the assumption is made that  $V_A \neq \infty$ . (i.e., has a nontrivial effect on the circuit). If  $V_A = \infty$ , then the early effect would be gone and the two circuits would behave similarly as a current source).

(ii) Find output impedances of the circuits.



Clearly output impedance =  $r_o$ .



Do KCL on left node:  $\frac{V_{\pi}}{R_{\pi}} + \frac{V_{\pi}}{R_E} = g_m V_{\pi}$

assuming  $V_{\pi} \neq 0$ :  $\frac{1}{R_{\pi}} \left( \frac{V_{\pi}}{R_{\pi}} + \frac{V_{\pi}}{R_E} \right) = \frac{1}{V_{\pi}} (g_m V_{\pi})$

$$\frac{1}{R_{\pi}} + \frac{1}{R_E} = g_m$$

This equation makes no sense, so  $V_{\pi} = 0$ .

Thus  $g_m V_{\pi} = 0$ , so no current flows through the VCCS  
so output impedance =  $r_o$  again.

The output impedances are the same, so it doesn't really support ~~the claim~~ the claim in part (i). It just shows that both circuits are affected by the early effect ( $r_o$  is related to  $V_A$ ). This is because the resulting change in  $V_{BE}$  (that helps to mitigate the early effect) is not a small-signal property.